Substitute for form 1449A/PTO

# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

*(use as many sheets as necessary)*

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| Complete if Known | |
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| Application Number | |
| Filing Date | |
| First Named Inventor | Seung Eon Moon |
| Art Unit | |
| Examiner Name | |
| Attorney Docket Number | 51876P400 |

## U.S. PATENT DOCUMENTS

| Examiner Initials* | Cite No.[1] | Document Number: Number - Kind Code[2] *(if known)* | Publication Date or Issue Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear |
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| SW | | KR 2001-77095 | 08-17-2001 | Samsung Electronics Co., Ltd. | | |
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| Examiner Signature | | Date Considered | 3/13/04 |
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*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication.

[1]Applicant's unique citation designation number (optional). [2]See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. [3]Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). [4]For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. [5]Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. [6]Applicant is to place a check mark here if English language Translation is attached.

# Information Disclosure Statement

New U.S. Patent Application for
MICROWAVE TUNABLE DEVICE HAVING
FERROELECTRIC/DIELECTRIC BST FILM
Our Ref. No.: P02EC054/US/jy

Reference No.:

(1) KR Laid-Open No. 2001-77095

(2) U.S. Patent No. 5,728,603

(3) High nonlinearity of $Ba_{0.6}Sr_{0.4}TiO_3$ films heteroepitaxially grown on MgO substrates
*(Applied Physics Letters, Vol. 77 No. 16, 16 October 2000, Pages 2587-2589)*

(4) Orientation dependent microwave dielectric properties of ferroelectric $Ba_{1-x}Sr_xTiO_3$ thin films
*(Applied Physic Letters, Vol. 83, No. 11, 15 September 2003, Pages 1-3)*